



Applicant:

Kulbinder K. Banger et al.

Serial No.:

10/698,118

Filing Date: October 31, 2003

Title:

SINGLE-SOURCE PRECURSORS FOR TERNARY CHALCOPYRITE

MATERIALS, AND METHODS OF MAKING AND USING THE SAME

Docket No.: 35089US1

INFORMATION DISCLOSURE STATEMENT

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with Rule 56, applicants are aware of the publications listed in the enclosed copy of Patent Office Form 1449. Since the Office has waived the requirement under 37 C.F.R §1.98(a)(2)(i) for submitting copies of cited U.S. patents and U.S. patent application publications, a copy of each listed U.S. patent or U.S. patent application publication is not being submitted herewith. Copies of all other cited documents are enclosed. Please charge any fee deficiencies and credit any overpayments to Deposit Account No. 16-0820, Order No. 35089US1.

> Respectfully submitted, PEARNE & GORDON LLP

Bv:

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Date: September 2, 2004

I hereby certify that the attached correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents, P.O. Box 1450. Alexandria, VA 22313-1450 on the date indicated below.

Steven J. Solomon

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Form PTO-1449		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY. DOCKET NO. 35089US1				SERIAL NO. 10/698,118		
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	E	E Tarrant, D., et al., "I-III-VI ₂ Multinary Solar Cells Based on CuInSe ₂ ", <i>Proc. 23rd IEEE Photovoltaic Specialist Conference</i> , 1993, pp. 372-378.							EE.		
	F	Shibata, J., et al., "Transmission Electron Microscopic Studies of LiNb0.5Ta0.5O3 Films Deposited on Sapphire Substrates by Thermal Plasma Spray CVD (Microstructure of LiNb0.5Ta0.5O3 Films Deposited by Thermal Plasma Spray CVD)", Materials Transactions, 2002, 43(7), pp. 1517-1524									
	G	Hollingsworth, J.A., et al., "Spray Chemical Vapor Deposition of CuInS ₂ Thin Films for Application in Solar Cell Devices", <i>Mat. Res. Soc. Symp. Proc.</i> , 1998, vol. 495, pp. 171-176.									
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Examiner:

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563-566.

Date Considered

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Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Harris, J.D., et al., "Using Single Source Precursors and Spray Chemical Vapor Deposition to Grow Thin-Film CuInS₂", *Proc. of the 28th IEEE Photovoltaic Specialists Conference*, 2000, pp.